INTEGRATED CIRCUITS

DATA SHEET

TZA3030 SDH/SONET STM1/OC3 optical receiver

Objective specification
File under Integrated Circuits, IC19





TZA3030

FEATURES

- Low equivalent input noise, typically 1 pA/√Hz
- Wide dynamic range, typically 0.5 μA to 2 mA
- On-chip low-pass filter. The bandwidth can be varied between 90 and 150 MHz using an external resistor. Default value is 120 MHz.
- Differential transimpedance of 1.8 $M\Omega$
- On-chip Automatic Gain Control (AGC)
- Positive Emitter Coupled Logic (PECL) or Current-Mode Logic (CML) compatible data outputs
- · LOS (Loss Of Signal) detection
- LOS threshold level can be adjusted using a single external resistor
- On-chip DC offset compensation
- Single supply voltage from 3.0 to 5.5 V
- Bias voltage for PIN diode.

APPLICATIONS

- Digital fibre optic receiver in short, medium and long haul optical telecommunications transmission systems or in high speed data networks
- Wideband RF gain block.

GENERAL DESCRIPTION

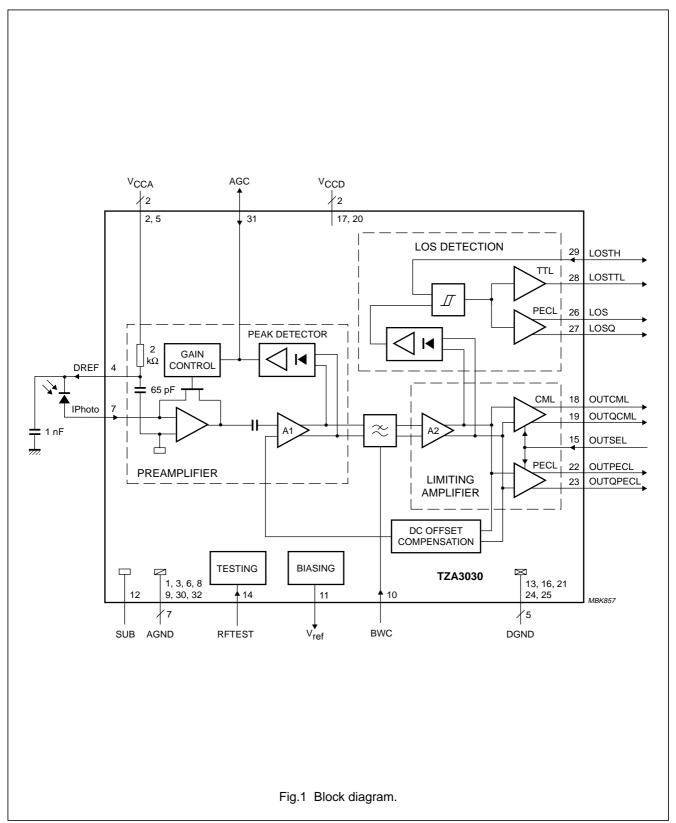
The TZA3030 optical receiver is a low-noise transimpedance amplifier with AGC plus a limiting amplifier designed to be used in SDH/SONET fibre optic links. The TZA3030 amplifies the current generated by a photo detector (PIN diode or avalanche photodiode) and converts it to a differential output voltage.

ORDERING INFORMATION

| TYPE | | PACKAGE | |
|-----------|--------|--|----------|
| NUMBER | NAME | DESCRIPTION | VERSION |
| TZA3030HL | LQFP32 | plastic low profile quad flat package; 32 leads; body $5 \times 5 \times 1.4$ mm | SOT401-1 |
| TZA3030U | _ | naked die in waffle pack carriers; die dimensions 1.58 × 1.58 mm | _ |

TZA3030

BLOCK DIAGRAM



3

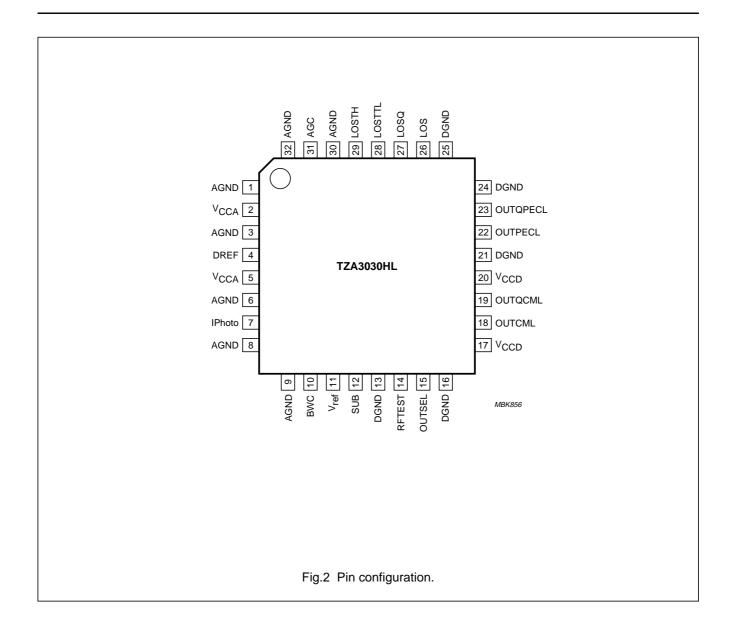
SDH/SONET STM1/OC3 optical receiver

TZA3030

PINNING

| SYMBOL | PIN | TYPE | DESCRIPTION |
|------------------|-----|---------------|---|
| AGND | 1 | ground | analog ground |
| V _{CCA} | 2 | supply | analog supply voltage |
| AGND | 3 | ground | analog ground |
| DREF | 4 | analog output | bias voltage for PIN diode (V _{CCA}); cathode should be connected to this pin |
| V _{CCA} | 5 | supply | analog supply voltage |
| AGND | 6 | ground | analog ground |
| IPhoto | 7 | analog input | current input; connect the anode of PIN diode to this pin; DC bias level is 1048 mV |
| AGND | 8 | ground | analog ground |
| AGND | 9 | ground | analog ground |
| BWC | 10 | analog input | bandwidth control pin; default bandwidth is 120 MHz; a resistor should be connected between V_{ref} (pin 11) and BWC (pin 10) to decrease bandwidth, or between BWC (pin 10) and AGND to increase bandwidth |
| V _{ref} | 11 | analog output | band gap reference voltage; nominal value approximately 1.2 V |
| SUB | 12 | substrate | substrate pin; to be connected to AGND |
| DGND | 13 | ground | digital ground |
| RFTEST | 14 | analog input | test pin; not connected; not used in application |
| OUTSEL | 15 | CMOS input | output select pin; when OUTSEL is HIGH, CML data outputs are active and PECL data outputs are disabled; OUTSEL is pulled LOW if left unconnected, PECL data outputs will then be active and CML data outputs disabled |
| DGND | 16 | ground | digital ground |
| V _{CCD} | 17 | supply | digital supply voltage |
| OUTCML | 18 | CML output | CML data output; OUTCML goes HIGH when current flows into IPhoto (pin 7) |
| OUTQCML | 19 | CML output | CML compliment of OUTCML (pin 18) |
| V _{CCD} | 20 | supply | digital supply voltage |
| DGND | 21 | ground | digital ground |
| OUTPECL | 22 | PECL output | PECL data output; OUTPECL goes HIGH when current flows into IPhoto (pin 7) |
| OUTQPECL | 23 | PECL output | PECL compliment of OUTPECL (pin 22) |
| DGND | 24 | ground | digital ground |
| DGND | 25 | ground | digital ground |
| LOS | 26 | PECL output | PECL-compatible LOS detection pin; LOS output is HIGH when the input signal is below the user programmable threshold level |
| LOSQ | 27 | PECL output | PECL compliment of LOS (pin 26) |
| LOSTTL | 28 | TTL output | CMOS-compatible LOS detection pin; the LOSTTL output is HIGH when the input signal is below the user programmable threshold level |
| LOSTH | 29 | analog I/O | pin for setting input threshold level; nominal DC voltage is $V_{CCA}-1.5~V$; threshold level set by connecting an external resistor between LOSTH and V_{CCA} or by forcing a current into LOSTH; default value for this resistor is 400 k Ω |
| AGND | 30 | ground | analog ground |
| AGC | 31 | analog I/O | AGC monitor voltage; the internal AGC circuit can be disabled by applying an external voltage to this pin |
| AGND | 32 | ground | analog ground |

TZA3030



SDH/SONET STM1/OC3 optical receiver

TZA3030

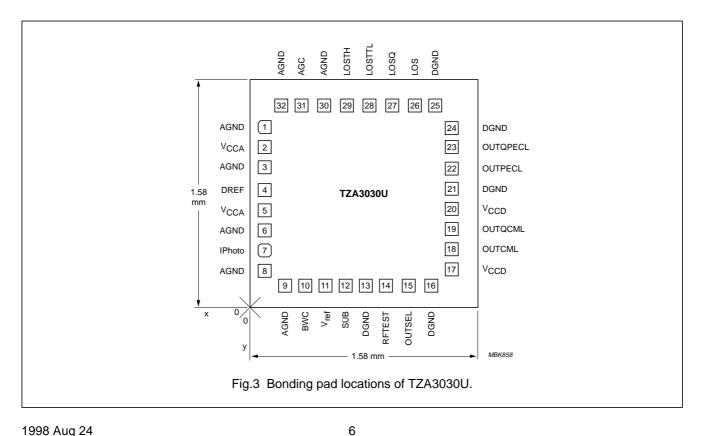
CHIP DIMENSIONS AND BONDING PAD LOCATIONS

| SYMBOL | PAD | COORDIN | IATES ⁽¹⁾ |
|------------------|-----|---------|----------------------|
| STWIBOL | PAD | x | у |
| AGND | 1 | 102 | 1251 |
| V _{CCA} | 2 | 102 | 1 111 |
| AGND | 3 | 102 | 971 |
| DREF | 4 | 102 | 814 |
| V _{CCA} | 5 | 102 | 674 |
| AGND | 6 | 102 | 534 |
| IPhoto | 7 | 102 | 395 |
| AGND | 8 | 102 | 254 |
| AGND | 9 | 243 | 105 |
| BWC | 10 | 383 | 105 |
| V _{ref} | 11 | 523 | 105 |
| SUB | 12 | 663 | 105 |
| DGND | 13 | 803 | 105 |
| RFTEST | 14 | 943 | 105 |
| OUTSEL | 15 | 1100 | 105 |
| DGND | 16 | 1257 | 105 |
| V _{CCD} | 17 | 1398 | 263 |
| OUTCML | 18 | 1398 | 403 |

| CVMPOL | PAD | COORDINATES ⁽¹⁾ | | | | |
|------------------|-----|----------------------------|------|--|--|--|
| SYMBOL | PAD | х | у | | | |
| OUTQCML | 19 | 1398 | 543 | | | |
| V _{CCD} | 20 | 1398 | 683 | | | |
| DGND | 21 | 1398 | 823 | | | |
| OUTPECL | 22 | 1398 | 963 | | | |
| OUTQPECL | 23 | 1398 | 1103 | | | |
| DGND | 24 | 1398 | 1243 | | | |
| DGND | 25 | 1283 | 1400 | | | |
| LOS | 26 | 1143 | 1400 | | | |
| LOSQ | 27 | 986 | 1400 | | | |
| LOSTTL | 28 | 829 | 1400 | | | |
| LOSTH | 29 | 671 | 1400 | | | |
| AGND | 30 | 514 | 1400 | | | |
| AGC | 31 | 357 | 1400 | | | |
| AGND | 32 | 217 | 1400 | | | |

Note

1. All coordinates (µm) are measured with respect to the bottom left-hand corner of the die.



SDH/SONET STM1/OC3 optical receiver

TZA3030

FUNCTIONAL DESCRIPTION

The TZA3030 contains five functional blocks:

- · Preamplifier input stage
- · Low-pass filter
- · Limiting amplifier stage
- · Offset compensation loop
- · Loss of signal detection unit.

Preamplifier

The preamplifier provides low-noise amplification of the current generated by a photodiode connected to pin IPhoto.

A differential amplifier converts the output of the preamplifier to a differential voltage. An AGC loop increases the dynamic range of the receiver by reducing the feedback resistance of the preamplifier. The AGC loop hold capacitor is integrated on-chip, so an external capacitor is not needed for AGC. The AGC voltage can be monitored at pin AGC. This pin can be left unconnected for normal operation. It can also be used to force an external AGC voltage. If pin AGC is connected to V_{CCA} , the internal AGC loop is disabled and the receiver gain is at a maximum. In this case, the maximum input current is approximately 10 μA .

Low-pass filter

A low-pass filter controls the bandwidth of the receiver, which can be varied between 90 and 150 MHz. The bandwidth is set to 120 MHz by default. It can be decreased by connecting a resistor between pin BWC and pin V_{ref} or increased by connecting a resistor between pin BWC and AGND.

Limiting amplifier

A limiting amplifier boosts the signal up to PECL levels. The output can be either CML or PECL compatible, selected by means of pin OUTSEL. When OUTSEL is HIGH, the CML data outputs are active and the PECL data outputs are disabled. If OUTSEL is left unconnected, it is pulled LOW and the PECL data outputs are active while the CML data outputs are disabled.

The logic level symbol definitions for CML and PECL are shown in Fig.4.

The CML and PECL output circuits are given in Fig.5.

Offset compensation loop

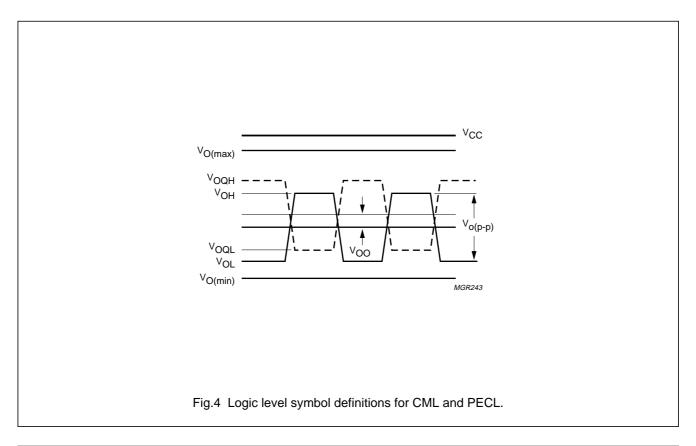
A control loop connected between the limiting amplifier output and the differential amplifier input cancels the DC offset. The loop bandwidth is fixed internally at 30 kHz.

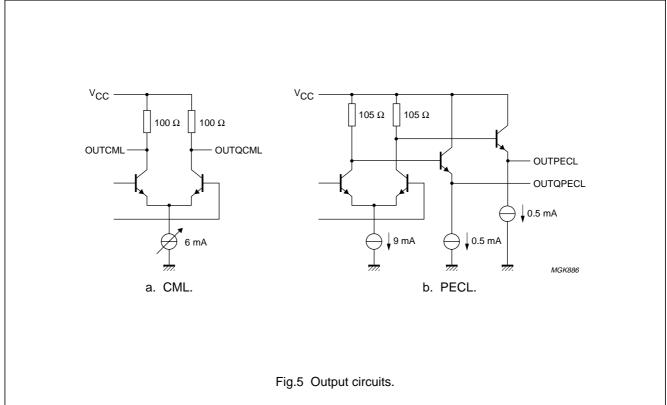
Loss Of Signal (LOS) detection

The LOS section detects an input signal level below a fixed threshold. The threshold is determined by the current through pin LOSTH. If this current is increased, the threshold level will rise. An external resistor connected between pin LOSTH and V_{CCA} can be used, or a current can be forced into pin LOSTH. The default value for the external resistor is 400 k Ω . In this case, the current through pin LOSTH will be approximately 3.75 µA since the voltage at pin LOSTH is regulated at 1.5 V below the supply voltage. This threshold corresponds to an input current of 208 nA. The ratio of LOSTH current to input current is thus approximately 18:1. When the input signal level falls below this threshold, the LOS (PECL compatible) and LOSTTL (TTL compatible) outputs go HIGH. The hysteresis is fixed internally at 3 dB. Response time is typically less than 20 µs.

SDH/SONET STM1/OC3 optical receiver

TZA3030





8

SDH/SONET STM1/OC3 optical receiver

TZA3030

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT |
|------------------|---|---------------------|-----------------------|------|
| Vcc | supply voltage | -0.5 | +6 | V |
| V _n | DC voltage | | | |
| | pin 7: IPhoto | -0.5 | +2 | V |
| | pin 14: RFTEST | -0.5 | V _{CC} + 0.5 | V |
| | pins 22, 23, 26 and 27: OUTPECL, OUTQPECL, LOS and LOSQ | V _{CC} – 2 | V _{CC} + 0.5 | V |
| | pins 18 and 19: OUTCML and OUTQCML | V _{CC} – 2 | V _{CC} + 0.5 | V |
| | pin 29: LOSTH | -0.5 | V _{CC} + 0.5 | V |
| | pin 10: BWC | -0.5 | +3.2 | V |
| | pin 31: AGC | -0.5 | V _{CC} + 0.5 | V |
| | pin 11: V _{ref} | -0.5 | +3.2 | V |
| | pin 4: DREF | -0.5 | V _{CC} + 0.5 | V |
| | pin 15: OUTSEL | -0.5 | V _{CC} + 0.5 | V |
| | pin 28: LOSTTL | -0.5 | V _{CC} + 0.5 | V |
| In | DC current | | | |
| | pin 7: IPhoto | -2.5 | +2.5 | mA |
| | pin 14: RFTEST | -2 | +2 | mA |
| | pins 22, 23, 26 and 27: OUTPECL, OUTQPECL, LOS and LOSQ | -25 | +10 | mA |
| | pins 18 and 19: OUTCML and OUTQCML | -15 | +15 | mA |
| | pin 29: LOSTH | -2 | +2 | mA |
| | pin 10: BWC | -1 | +1 | mA |
| | pin 31: AGC | -0.2 | +0.2 | mA |
| | pin 11: V _{ref} | -2 | +2.5 | mA |
| | pin 4: DREF | -2.5 | +2.5 | mA |
| | pin 15: OUTSEL | -0.5 | +0.5 | mA |
| | pin 28: LOSTTL | -16 | +16 | mA |
| P _{tot} | total power dissipation | _ | 600 | mW |
| T _{stg} | storage temperature | -65 | +150 | °C |
| Tj | junction temperature | | 150 | °C |
| T _{amb} | operating ambient temperature | -40 | +85 | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | VALUE | UNIT |
|----------------------|--|-------|------|
| R _{th(j-s)} | thermal resistance from junction to solder point | tbf | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | tbf | K/W |

SDH/SONET STM1/OC3 optical receiver

TZA3030

CHARACTERISTICS

For typical values T_{amb} = 25 °C and V_{CC} = 5 V; minimum and maximum values are valid over the entire ambient temperature range and process spread.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-----------------------------|---|---|------------------------|---------|------------------------|-------|
| V _{CC} | supply voltage | | 3 | 5 | 5.5 | V |
| I _{CCD} | digital supply current | note 1 | 13 | 20 | 28 | mA |
| | | note 2 | _ | 47 | _ | mA |
| | | note 3 | 11 | 17 | 24 | mA |
| I _{CCA} | analog supply current | | 24 | 36 | 51 | mA |
| P _{tot} | total power dissipation | | _ | _ | 525 | mW |
| Tj | junction temperature | | -40 | _ | +110 | °C |
| T _{amb} | operating ambient temperature | | -40 | +25 | +85 | °C |
| R _{tr} | small-signal transresistance | measured differentially | | | | |
| | of the receiver | PECL outputs | _ | 2000 | _ | kΩ |
| | | CML outputs | _ | 1000 | _ | kΩ |
| f _{-3dB(h)} | high frequency –3 dB point | pin BWC left unconnected; note 4 | _ | 120 | - | MHz |
| f _{-3dB(I)} | low frequency -3 dB point | | 20 | 30 | 40 | kHz |
| I _{n(tot)} | total integrated RMS noise current over bandwidth | referenced to input; C _i = 1.2 pF; note 5 | | | | |
| | | $\Delta f = 90 \text{ MHz}$ | _ | 16 | _ | nA |
| | | $\Delta f = 120 \text{ MHz}$ | _ | tbf | _ | nA |
| | | $\Delta f = 155 \text{ MHz}$ | _ | tbf | _ | nA |
| PSRR | power supply rejection ratio | measured differentially; note 6 | | | | |
| | | f = 100 kHz to 10 MHz | _ | 0.5 | | μA/V |
| | | f = 10 MHz to 100 MHz | _ | 10 | | μA/V |
| $\Delta R_{tr}/\Delta t$ | AGC loop constant | | _ | 1 | _ | dB/ms |
| Input: IPho | oto | | | • | | • |
| V _{bias(IPhoto)} | input bias voltage | | tbf | 1048 | tbf | mV |
| I _{i(IPhoto)(p-p)} | input current (peak-to-peak | V _{CC} = 5 V | -2000 | +1 | +2000 | μΑ |
| , , , , , , , | value) | V _{CC} = 3.3 V | -1000 | +1 | +1000 | μΑ |
| PECL outp | outs: OUTPECL and OUTQPE | CL | | | ! | |
| V _{OH} | HIGH-level output voltage | 50 Ω to V _{CC} – 2 V | V _{CC} – 1100 | <u></u> | V _{CC} – 900 | mV |
| V _{OL} | LOW-level output voltage | 50 Ω to V _{CC} – 2 V | V _{CC} – 1840 | _ | V _{CC} – 1620 | mV |
| V ₀₀ | output offset voltage | measured differentially | -10 | _ | +10 | mV |
| t _r | rise time | 20% to 80% | _ | tbf | tbf | ps |
| t _f | fall time | 80% to 20% | _ | tbf | tbf | ps |

SDH/SONET STM1/OC3 optical receiver

TZA3030

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------------------|--|---|------------------------|-----------------------|------------------------|------|
| PECL outp | outs: LOS and LOSQ | | | | | • |
| V _{OH} | HIGH-level output voltage | 50 Ω to V _{CC} – 2 V | V _{CC} – 1100 | _ | V _{CC} – 900 | mV |
| V _{OL} | LOW-level output voltage | 50 Ω to V _{CC} – 2 V | V _{CC} - 1840 | _ | V _{CC} – 1620 | mV |
| V _{oo} | output offset voltage | measured differentially | -10 | _ | +10 | mV |
| t _r | rise time | 20% to 80% | _ | _ | 600 | ns |
| t _f | fall time | 80% to 20% | 1- | _ | 200 | ns |
| CML outpu | uts: OUTCML and OUTQCML | | • | | | |
| Vo | output voltage | measured single-ended; 50 Ω to V _{CC} | V _{CC} – 260 | _ | V _{CC} | mV |
| V _{o(se)(p-p)} | output voltage single-ended (peak-to-peak value) | 50 Ω to V _{CC} | 150 | 200 | 260 | mV |
| V _{OO} | output offset voltage | measured differentially; 50 Ω to V_{CC} | -10 | _ | +10 | mV |
| R _o | output resistance | measured single-ended | 80 | 100 | 120 | Ω |
| t _r | rise time | 20% to 80%; R _L = 50 Ω; C _L = 1 pF | _ | tbf | _ | ps |
| t _f | fall time | 80% to 20%; $R_L = 50 \Omega$; $C_L = 1 pF$ | - | tbf | _ | ps |
| CMOS inpo | ut: OUTSEL | | | | | |
| V _{IL} | LOW-level input voltage | | _ | 0.4 | 0.8 | V |
| V _{IH} | HIGH-level input voltage | | V _{CC} – 1 | V _{CC} – 0.5 | _ | V |
| CMOS out | put: LOSTTL | | | | | |
| V _{OL} | LOW-level output voltage | | 0 | _ | 0.2 | V |
| V _{OH} | HIGH-level output voltage | | V _{CC} - 0.2 | _ | V _{CC} | V |

Notes

- 1. OUTPECL, OUTQPECL, OUTCML, OUTQCML, LOS and LOSQ outputs are left unconnected. OUTPECL and OUTQPECL outputs are active.
- 2. OUTPECL and OUTQPECL outputs are terminated with 50 Ω to V_T. V_T is an external termination voltage for PECL outputs and is 2 V below the supply voltage. OUTCML, OUTQCML, LOS and LOSQ outputs are left unconnected.
- 3. OUTCML and OUTQCML outputs are terminated with 50 Ω to V_{CCD}; CML outputs are active. OUTQPECL, OUTQPECL, LOS and LOSQ outputs are left unconnected.
- 4. The bandwidth is set to 120 MHz by default. It can be varied between 90 and 150 MHz by adjusting the voltage at pin BWC.
- 5. All $I_{n(tot)}$ measurements were made with an input capacitance of $C_i = 1.2$ pF. This was comprised of 0.7 pF for the photodiode itself, with 0.3 pF allowed for the PCB layout and 0.2 pF intrinsic to the package.
- 6. PSRR is defined as the ratio of the equivalent current change at the input (ΔI_{IPhoto}) to a change in supply voltage:

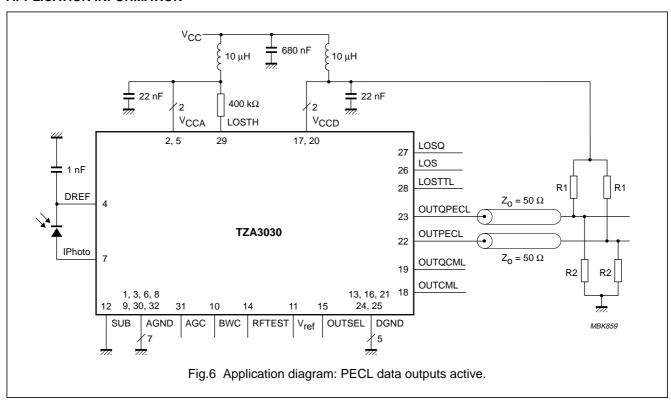
$$\text{PSRR} = \frac{\Delta I_{\text{IPhoto}}}{\Delta V_{\text{CC}}}$$

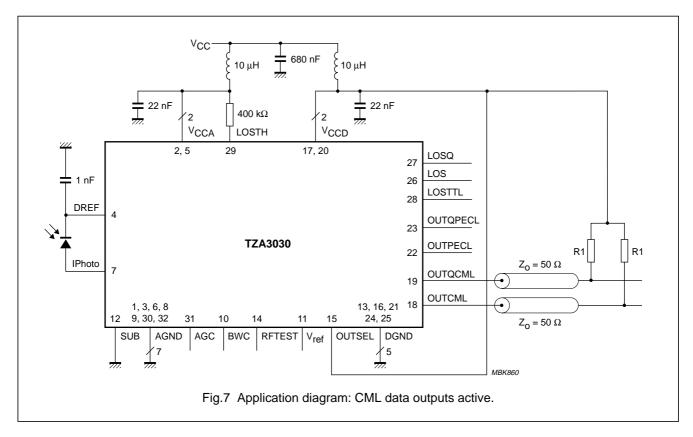
For example, a 4 mV disturbance on V_{CC} at 10 MHz will typically generate the equivalent of 2 nA extra photodiode current.

SDH/SONET STM1/OC3 optical receiver

TZA3030

APPLICATION INFORMATION



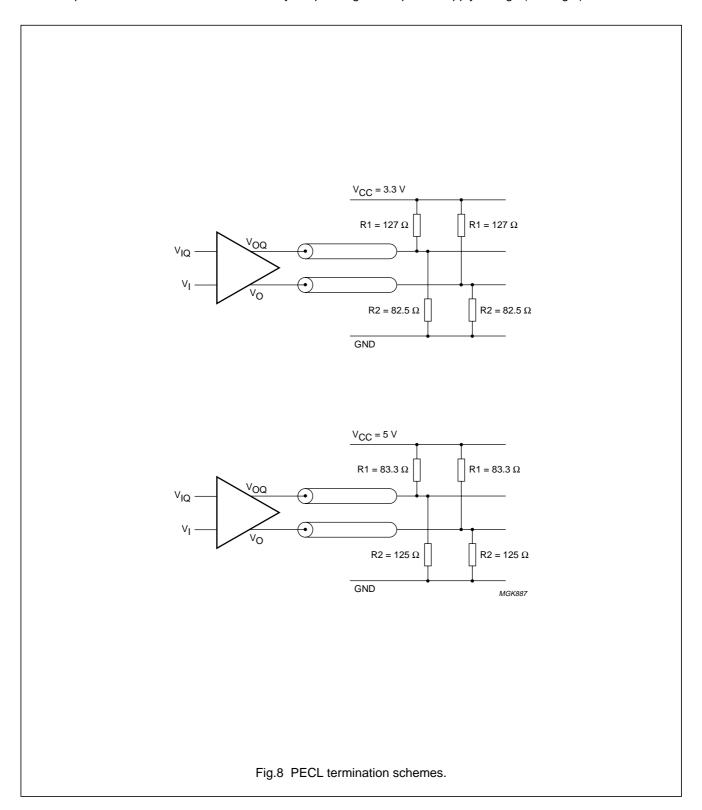


SDH/SONET STM1/OC3 optical receiver

TZA3030

PECL outputs: OUTPECL, OUTQPECL, LOS and LOSQ

PECL outputs can be terminated in different ways depending on the power supply voltage (see Fig.8).



SDH/SONET STM1/OC3 optical receiver

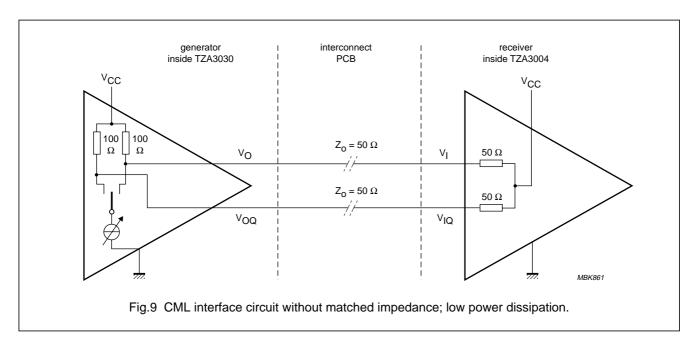
TZA3030

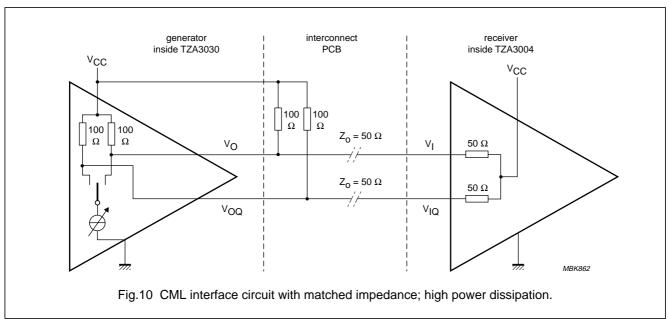
CML outputs: OUTCML and OUTQCML

The output impedance of the CML output driver is 100 Ω (see Fig.9) which doesn't match the characteristic impedance of the strip line. While this means that the reflections of some incident edges will arrive at the driver output on the PCB, this value was selected to reduce power dissipation inside the IC. The parallel combination of 100 Ω and 50 Ω (33 Ω) will generate a signal swing of 200 mV (peak-to-peak value, single-sided) with a tail current of 6 mA.

If the output impedance was 50 Ω rather than 100 Ω , an 8 mA tail current would be needed to generate the same voltage swing. This would increase power dissipation by 33%.

If necessary, the output impedance of the generator can be matched to the line impedance by connecting an external 100 Ω resistor in parallel with the output as shown in Fig.10. The magnitude of the output voltage swing will not change due to adaptive regulation. However, power dissipation will increase by 33%.





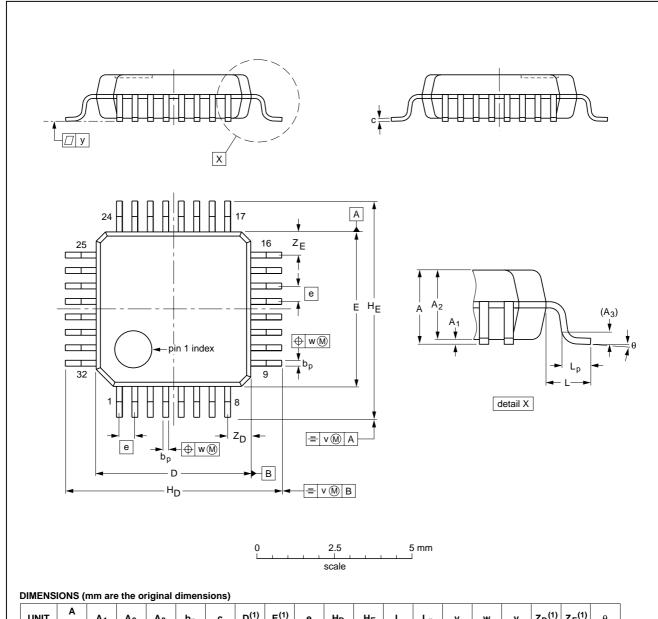
SDH/SONET STM1/OC3 optical receiver

TZA3030

PACKAGE OUTLINE

LQFP32: plastic low profile quad flat package; 32 leads; body 5 x 5 x 1.4 mm

SOT401-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | C | D ⁽¹⁾ | E ⁽¹⁾ | е | H _D | HE | L | Lp | v | w | у | Z _D ⁽¹⁾ | Z _E ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|----------------|--------------|--------------|------------------|------------------|-----|----------------|--------------|-----|--------------|-----|------|-----|-------------------------------|-------------------------------|----------|
| mm | 1.60 | 0.15 0.05 | 1.5 1.3 | 0.25 | 0.27 0.17 | 0.18 0.12 | 5.1 4.9 | 5.1 4.9 | 0.5 | 7.15 6.85 | 7.15 6.85 | 1.0 | 0.75 0.45 | 0.2 | 0.12 | 0.1 | 0.95 0.55 | 0.95 0.55 | 7° 0° |

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE | TLINE REFERENCES | | | | | ISSUE DATE |
|----------|------------------|-------|------|--|------------|---------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE |
| SOT401-1 | | | | | | 95-12-19 97-08-04 |

SDH/SONET STM1/OC3 optical receiver

TZA3030

SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "Data Handbook IC26; Integrated Circuit Packages" (order code 9398 652 90011).

Reflow soldering

Reflow soldering techniques are suitable for all LQFP packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 50 and 300 seconds depending on heating method. Typical reflow peak temperatures range from 215 to 250 °C.

Wave soldering

Wave soldering is **not** recommended for LQFP packages. This is because of the likelihood of solder bridging due to closely-spaced leads and the possibility of incomplete solder penetration in multi-lead devices.

CAUTION

Wave soldering is NOT applicable for all LQFP packages with a pitch (e) equal or less than 0.5 mm.

If wave soldering cannot be avoided, for LQFP packages with a pitch (e) larger than 0.5 mm, the following conditions must be observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The footprint must be at an angle of 45° to the board direction and must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Repairing soldered joints

Fix the component by first soldering two diagonally-opposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 $^{\circ}$ C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^{\circ}$ C.

SDH/SONET STM1/OC3 optical receiver

TZA3030

DEFINITIONS

| Data sheet status | | | | |
|---|---|--|--|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | | | |
| Product specification | This data sheet contains final product specifications. | | | |
| Limiting values | | | | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | | | |

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

TZA3030

NOTES

TZA3030

NOTES

Philips Semiconductors – a worldwide company

Argentina: see South America

Australia: 34 Waterloo Road, NORTH RYDE, NSW 2113,

Tel. +61 2 9805 4455, Fax. +61 2 9805 4466

Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213, Tel. +43 160 1010,

Fax. +43 160 101 1210

Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,

220050 MINSK, Tel. +375 172 200 733, Fax. +375 172 200 773

Belgium: see The Netherlands **Brazil:** see South America

Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor,

51 James Bourchier Blvd., 1407 SOFIA, Tel. +359 2 689 211, Fax. +359 2 689 102

Canada: PHILIPS SEMICONDUCTORS/COMPONENTS,

Tel. +1 800 234 7381

China/Hong Kong: 501 Hong Kong Industrial Technology Centre,

72 Tat Chee Avenue, Kowloon Tong, HONG KONG,

Tel. +852 2319 7888, Fax. +852 2319 7700

Colombia: see South America
Czech Republic: see Austria

Denmark: Prags Boulevard 80, PB 1919, DK-2300 COPENHAGEN S,

Tel. +45 32 88 2636, Fax. +45 31 57 0044 **Finland:** Sinikalliontie 3, FIN-02630 ESPOO, Tel. +358 9 615800, Fax. +358 9 61580920

France: 51 Rue Carnot, BP317, 92156 SURESNES Cedex,

Tel. +33 1 40 99 6161, Fax. +33 1 40 99 6427

Germany: Hammerbrookstraße 69, D-20097 HAMBURG,

Tel. +49 40 23 53 60, Fax. +49 40 23 536 300

Greece: No. 15, 25th March Street, GR 17778 TAVROS/ATHENS,

Tel. +30 1 4894 339/239, Fax. +30 1 4814 240

Hungary: see Austria

India: Philips INDIA Ltd, Band Box Building, 2nd floor, 254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025.

Tel. +91 22 493 8541, Fax. +91 22 493 0966

 $\textbf{Indonesia:} \ \mathsf{PT} \ \mathsf{Philips} \ \mathsf{Development} \ \mathsf{Corporation}, \ \mathsf{Semiconductors} \ \mathsf{Division},$

Gedung Philips, Jl. Buncit Raya Kav.99-100, JAKARTA 12510, Tel. +62 21 794 0040 ext. 2501, Fax. +62 21 794 0080

Ireland: Newstead, Clonskeagh, DUBLIN 14, Tel. +353 1 7640 000, Fax. +353 1 7640 200

Israel: RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053, TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

Italy: PHILIPS SEMICONDUCTORS, Piazza IV Novembre 3, 20124 MILANO, Tel. +39 2 6752 2531, Fax. +39 2 6752 2557

Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108-8507, Tel. +81 3 3740 5130, Fax. +81 3 3740 5077

Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL,

Tel. +82 2 709 1412, Fax. +82 2 709 1415

Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,

Tel. +60 3 750 5214, Fax. +60 3 757 4880

Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,

Tel. +9-5 800 234 7381

Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,

Tel. +31 40 27 82785, Fax. +31 40 27 88399

New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,

Tel. +64 9 849 4160, Fax. +64 9 849 7811 **Norway:** Box 1, Manglerud 0612, OSLO, Tel. +47 22 74 8000, Fax. +47 22 74 8341

Pakistan: see Singapore

Philippines: Philips Semiconductors Philippines Inc., 106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI, Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

Poland: Ul. Lukiska 10, PL 04-123 WARSZAWA, Tel. +48 22 612 2831, Fax. +48 22 612 2327

Portugal: see Spain Romania: see Italy

Russia: Philips Russia, UI. Usatcheva 35A, 119048 MOSCOW,

Tel. +7 095 755 6918, Fax. +7 095 755 6919

Singapore: Lorong 1, Toa Payoh, SINGAPORE 319762,

Tel. +65 350 2538, Fax. +65 251 6500

Slovakia: see Austria Slovenia: see Italy

South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,

2092 JOHANNESBURG, P.O. Box 7430 Johannesburg 2000,

Tel. +27 11 470 5911, Fax. +27 11 470 5494 **South America:** Al. Vicente Pinzon, 173, 6th floor,

04547-130 SÃO PAULO, SP, Brazil, Tel. +55 11 821 2333, Fax. +55 11 821 2382

Spain: Balmes 22, 08007 BARCELONA, Tel. +34 93 301 6312, Fax. +34 93 301 4107

Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM,

Tel. +46 8 5985 2000, Fax. +46 8 5985 2745 **Switzerland:** Allmendstrasse 140, CH-8027 ZÜRICH, Tel. +41 1 488 2741 Fax. +41 1 488 3263

Taiwan: Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1, TAIPEI, Taiwan Tel. +886 2 2134 2865, Fax. +886 2 2134 2874

Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd.,

209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260, Tel. +66 2 745 4090, Fax. +66 2 398 0793

Turkey: Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL,

Tel. +90 212 279 2770, Fax. +90 212 282 6707

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,

252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes, MIDDLESEX UB3 5BX, Tel. +44 181 730 5000, Fax. +44 181 754 8421 United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,

Tel. +1 800 234 7381

Uruguay: see South America **Vietnam:** see Singapore

Yugoslavia: PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD,

Tel. +381 11 625 344, Fax.+381 11 635 777

For all other countries apply to: Philips Semiconductors, International Marketing & Sales Communications, Building BE-p, P.O. Box 218, 5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

Internet: http://www.semiconductors.philips.com

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

© Philips Electronics N.V. 1998

425102/200/01/pp20

Date of release: 1998 Aug 24 Document order number: 9397 750 04069

Let's make things better.







SCA60